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# **Dual Binary to 1-of-4 Decoder/Demultiplexer**

The MC14555B and MC14556B are constructed with complementary MOS (CMOS) enhancement mode devices. Each Decoder/Demultiplexer has two select inputs (A and B), an active low Enable input (E), and four mutually exclusive outputs (Q0, Q1, Q2, Q3). The MC14555B has the selected output go to the "high" state, and the MC14556B has the selected output go to the "low" state. Expanded decoding such as binary—to—hexadecimal (1—of—16), etc., can be achieved by using other MC14555B or MC14556B devices.

Applications include code conversion, address decoding, memory selection control, and demultiplexing (using the Enable input as a data input) in digital data transmission systems.

#### **Features**

- Diode Protection on All Inputs
- Active High or Active Low Outputs
- Expandable
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- All Outputs Buffered
- Capable of Driving Two Low-Power TTL Loads or One Low-Power Schottky TTL Load Over the Rated Temperature Range
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

#### MAXIMUM RATINGS (Voltages Referenced to Voc.)

(Voltages Referenced to VSS)						
Parameter	Symbol	Value	Unit			
DC Supply Voltage Range	$V_{DD}$	-0.5 to +18.0	V			
Input or Output Voltage Range (DC or Transient)	V <sub>in</sub> , V <sub>out</sub>	-0.5 to V <sub>DD</sub> + 0.5	V			
Input or Output Current (DC or Transient) per Pin	I <sub>in</sub> , I <sub>out</sub>	±10	mA			
Power Dissipation, per Package (Note 1)	P <sub>D</sub>	500	mW			
Ambient Temperature Range	T <sub>A</sub>	-55 to +125	°C			
Storage Temperature Range	T <sub>stg</sub>	-65 to +150	°C			
Lead Temperature (8–Second Soldering)	TL	260	°C			

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Temperature Derating: "D/DW" Packages: -7.0 mW/°C From 65°C To 125°C This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation,  $V_{in}$  and  $V_{out}$  should be constrained to the range  $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$ .

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either  $V_{SS}$  or  $V_{DD}$ ). Unused outputs must be left open.



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SOIC-16 D SUFFIX CASE 751B



SOEIAJ-16 F SUFFIX CASE 966

#### **PIN ASSIGNMENTS**

			_				_
Ē <sub>A</sub> [	1 ●	16	] V <sub>DD</sub>	Ē <sub>A</sub> [	1 ●	16	D V <sub>DC</sub>
A <sub>A</sub> [	2	15	] Ē <sub>B</sub>	A <sub>A</sub> [	2	15	ΕB
ВА	3	14	] A <sub>B</sub>	ВА	3	14	A <sub>B</sub>
Q0 <sub>A</sub>	4	13	] B <sub>B</sub>	Q0 <sub>A</sub> [	4	13	] В <sub>В</sub>
Q1 <sub>A</sub>	5	12	] Q0 <sub>B</sub>	Q <sub>1A</sub> [	5	12	Q0 <sub>E</sub>
Q2 <sub>A</sub>	6	11	] Q1 <sub>B</sub>	<b>Q</b> 2 <sub>A</sub> [	6	11	Q1 <sub>E</sub>
Q3 <sub>A</sub> [	7	10	] Q2 <sub>B</sub>	Q3 <sub>A</sub> [	7	10	Q2 <sub>E</sub>
V <sub>SS</sub> [	8	9	Q3 <sub>B</sub>	V <sub>SS</sub> [	8	9	Q3 <sub>E</sub>

MC14555B

MC14556B

#### MARKING DIAGRAMS



SOIC-16



SOEIAJ-16

x = 5 or 6

A = Assembly Location

WL, L = Wafer Lot YY, Y = Year WW, W = Work Week G = Pb-Free Package

#### ORDERING INFORMATION

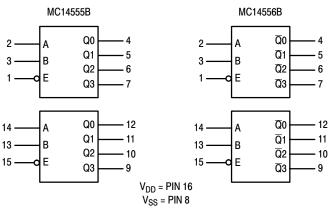
See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

#### **TRUTH TABLE**

Inputs			Outputs							
Enable	Select		MC14555B			N	/IC14	556	В	
Ē	В	Α	Q3	Q2	Q1	Q0	Q3	Q2	Q1	Q0
0	0	0	0	0	0	1	1	1	1	0
0	0	1	0	0	1	0	1	1	0	1
0	1	0	0	1	0	0	1	0	1	1
0	1	1	1	0	0	0	0	1	1	1
1	Χ	Х	0	0	0	0	1	1	1	1

X = Don't Care

## **BLOCK DIAGRAM**



#### **ELECTRICAL CHARACTERISTICS** (Voltages Referenced to V<sub>SS</sub>)

			- 5	5°C		25°C		12	5°C	
Characteristic	Symbol	V <sub>DD</sub> Vdc	Min	Max	Min	Typ (Note 2)	Max	Min	Max	Unit
Output Voltage "0" Level V <sub>in</sub> = V <sub>DD</sub> or 0	V <sub>OL</sub>	5.0 10 15	- - -	0.05 0.05 0.05	- - -	0 0 0	0.05 0.05 0.05	- - -	0.05 0.05 0.05	Vdc
V <sub>in</sub> = 0 or V <sub>DD</sub> "1" Level	V <sub>OH</sub>	5.0 10 15	4.95 9.95 14.95	- - -	4.95 9.95 14.95	5.0 10 15	- - -	4.95 9.95 14.95	- - -	Vdc
Input Voltage "0" Level (V <sub>O</sub> = 4.5 or 0.5 Vdc) (V <sub>O</sub> = 9.0 or 1.0 Vdc) (V <sub>O</sub> = 13.5 or 1.5 Vdc)	V <sub>IL</sub>	5.0 10 15	- - -	1.5 3.0 4.0	- - -	2.25 4.50 6.75	1.5 3.0 4.0	- - -	1.5 3.0 4.0	Vdc
"1" Level $(V_O = 0.5 \text{ or } 4.5 \text{ Vdc})$ $(V_O = 1.0 \text{ or } 9.0 \text{ Vdc})$ $(V_O = 1.5 \text{ or } 13.5 \text{ Vdc})$	V <sub>IH</sub>	5.0 10 15	3.5 7.0 11	- - -	3.5 7.0 11	2.75 5.50 8.25	- - -	3.5 7.0 11	- - -	Vdc
Output Drive Current (V <sub>OH</sub> = 2.5 Vdc) Source (V <sub>OH</sub> = 4.6 Vdc) (V <sub>OH</sub> = 9.5 Vdc) (V <sub>OH</sub> = 13.5 Vdc)	I <sub>OH</sub>	5.0 5.0 10 15	-3.0 -0.64 -1.6 -4.2	- - - -	-2.4 -0.51 -1.3 -3.4	-4.2 -0.88 -2.25 -8.8	- - - -	-1.7 -0.36 -0.9 -2.4	- - - -	mAdc
$(V_{OL} = 0.4 \text{ Vdc})$ Sink $(V_{OL} = 0.5 \text{ Vdc})$ $(V_{OL} = 1.5 \text{ Vdc})$	I <sub>OL</sub>	5.0 10 15	0.64 1.6 4.2	- - -	0.51 1.3 3.4	0.88 2.25 8.8	- - -	0.36 0.9 2.4	- - -	mAdc
Input Current	I <sub>in</sub>	15	_	±0.1	-	±0.00001	±0.1	-	±1.0	μAdc
Input Capacitance, (V <sub>in</sub> = 0)	C <sub>in</sub>	-	_	-	-	5.0	7.5	_	-	pF
Quiescent Current (Per Package)	I <sub>DD</sub>	5.0 10 15	- - -	5.0 10 20	- - -	0.005 0.010 0.015	5.0 10 20	- - -	150 300 600	μAdc
Total Supply Current (Notes 3, 4) (Dynamic plus Quiescent, Per Package) (C <sub>L</sub> = 50 pF on all outputs, all buffers switching)	I <sub>T</sub>	5.0 10 15			$I_{T} = (1$	.85 μA/kHz) .70 μA/kHz) .60 μA/kHz)	f + I <sub>DD</sub>	<u>,                                      </u>	,	μAdc

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

- The formulas given are for the typical characteristics only at 25°C.
   To calculate total supply current at loads other than 50 pF: I<sub>T</sub>(C<sub>L</sub>) = I<sub>T</sub>(50 pF) + (C<sub>L</sub> 50) Vfk where: I<sub>T</sub> is in μA (per package), C<sub>L</sub> in pF, V = (V<sub>DD</sub> V<sub>SS</sub>) in volts, f in kHz is input frequency, and k = 0.002.

#### **SWITCHING CHARACTERISTICS** (Note 5) ( $C_L = 50 \text{ pF}, T_A = 25^{\circ}\text{C}$ )

Characteristic	Symbol	V <sub>DD</sub>	Min	Typ (Note 6)	Max	Unit
Output Rise and Fall Time $t_{TLH}$ , $t_{THL}$ = (1.5 ns/pF) $C_L$ + 25 ns $t_{TLH}$ , $t_{THL}$ = (0.75 ns/pF) $C_L$ + 12.5 ns $t_{TLH}$ , $t_{THL}$ = (0.55 ns/pF) $C_L$ + 9.5 ns	t <sub>TLH</sub> , t <sub>THL</sub>	5.0 10 15	- - -	100 50 40	200 100 80	ns
Propagation Delay Time – A, B to Output $t_{PLH}$ , $t_{PHL}$ = (1.7 ns/pF) $C_L$ + 135 ns $t_{PLH}$ , $t_{PHL}$ = (0.66 ns/pF) $C_L$ + 62 ns $t_{PLH}$ , $t_{PHL}$ = (0.5 ns/pF) $C_L$ + 45 ns	t <sub>PLH</sub> , t <sub>PHL</sub>	5.0 10 15	- - -	220 95 70	440 190 140	ns
Propagation Delay Time – E to Output $t_{PLH}$ , $t_{PHL}$ = (1.7 ns/pF) $C_L$ + 115 ns $t_{PLH}$ , $t_{PHL}$ = (0.66 ns/pF) $C_L$ + 52 ns $t_{PLH}$ , $t_{PHL}$ = (0.5 ns/pF) $C_L$ + 40 ns	t <sub>PLH</sub> , t <sub>PHL</sub>	5.0 10 15	- - -	200 85 65	400 170 130	ns

- 5. The formulas given are for the typical characteristics only at 25°C.
- 6. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

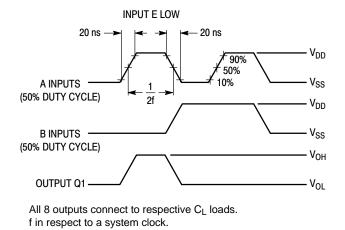


Figure 1. Dynamic Power Dissipation Signal Waveforms

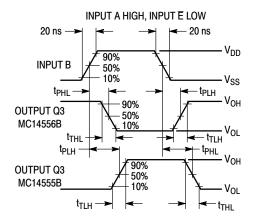
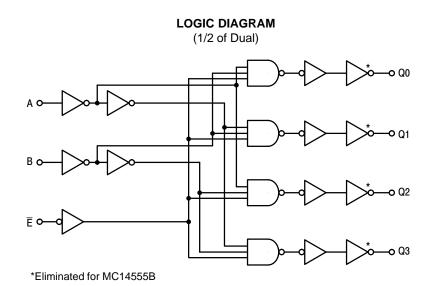


Figure 2. Dynamic Signal Waveforms



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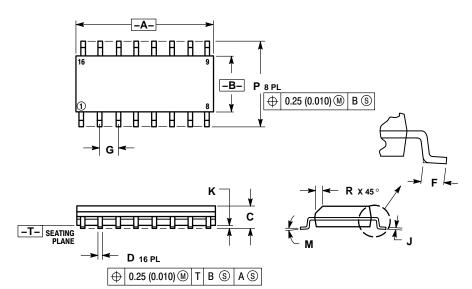
Device	Package	Shipping <sup>†</sup>
MC14555BDG	SOIC-16 (Pb-Free)	48 Units / Rail
MC14555BDR2G	SOIC-16 (Pb-Free)	2500 / Tape & Reel
NLV14555BDR2G*	SOIC-16 (Pb-Free)	2500 / Tape & Reel
MC14555BFELG	SOEIAJ-16 (Pb-Free)	2000 / Tape & Reel
MC14556BDR2G	SOIC-16 (Pb-Free)	2500 / Tape & Reel
NLV14556BDR2G*	SOIC-16 (Pb-Free)	2500 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
\*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP

Capable.

#### **PACKAGE DIMENSIONS**

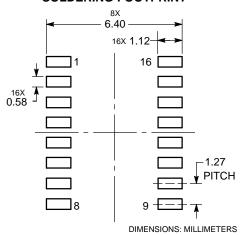
SOIC-16 CASE 751B-05 ISSUE K



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
  4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
  5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION. SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

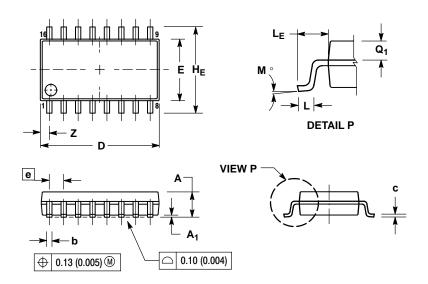
	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	9.80	10.00	0.386	0.393
В	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
ם	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27	BSC	0.050	BSC
7	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

#### **SOLDERING FOOTPRINT**



#### PACKAGE DIMENSIONS

#### SOEIAJ-16 CASE 966 ISSUE A



#### NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M. 1982.
- CONTROLLING DIMENSION: MILLIMETER.
   DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15
- (0.006) PER SIDE.

  4. TERMINAL NUMBERS ARE SHOWN FOR
- REFERENCE ONLY.

  5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α		2.05		0.081
A <sub>1</sub>	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
С	0.10	0.20	0.007	0.011
D	9.90	10.50	0.390	0.413
E	5.10	5.45	0.201	0.215
е	1.27 BSC		0.050	BSC
HE	7.40	8.20	0.291	0.323
L	0.50	0.85	0.020	0.033
LE	1.10	1.50	0.043	0.059
M	0 °	10 °	0 °	10°
Q <sub>1</sub>	0.70	0.90	0.028	0.035
Z		0.78		0.031

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